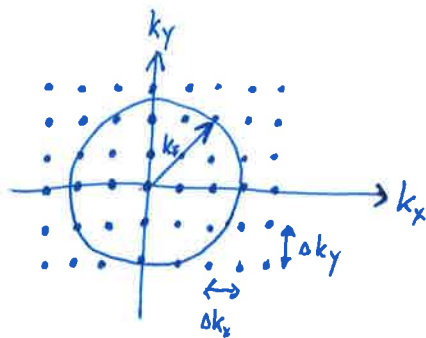


Quantum Transport

Solutions to problem sheet 3

1) Subband energy $\epsilon_N = \epsilon_{n_x} + \epsilon_{n_y} \leq E_F$

Square-well confinement \Rightarrow equidistant k -states, $\Delta k_i = \frac{\pi}{L_i}$
 $\Rightarrow \frac{\hbar^2 k_{trans}^2}{2m} = \frac{\hbar^2 (k_x^2 + k_y^2)}{2m} \leq E_F = \frac{\hbar^2 k_F^2}{2m}$ or $k_x^2 + k_y^2 \leq k_F^2$ (periodic boundary conditions)



If we assume $\Delta k_x \cdot \Delta k_y \ll k_F^2$ we can estimate the number of states inside the Fermi-circle as: cross-section

$$N \approx \frac{\pi k_F^2}{\Delta k_x \cdot \Delta k_y} = \frac{\pi k_F^2}{\frac{\pi}{L_x} \cdot \frac{\pi}{L_y}} = \frac{k_F^2}{\pi} L_x \cdot L_y \stackrel{\text{area of lead}}{=} \frac{A}{\lambda_F^2}$$

$\Rightarrow A \quad k_F = \frac{2\pi}{\lambda_F}$

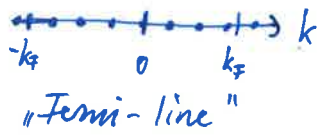
2a) conductance G vs. the voltage applied to the split-gate that defines the QPC.

b) The number of transmitted channels is not reduced continuously. One can think of a QPC as a "wire" in which the width is controlled by the gate.

c) Ideally, the channels are either fully transmitted or reflected.

d) The conductance value on a plateau is determined by the number of (fully) transmitted channels. Each channel can carry $2e^2/h$ in conductance.

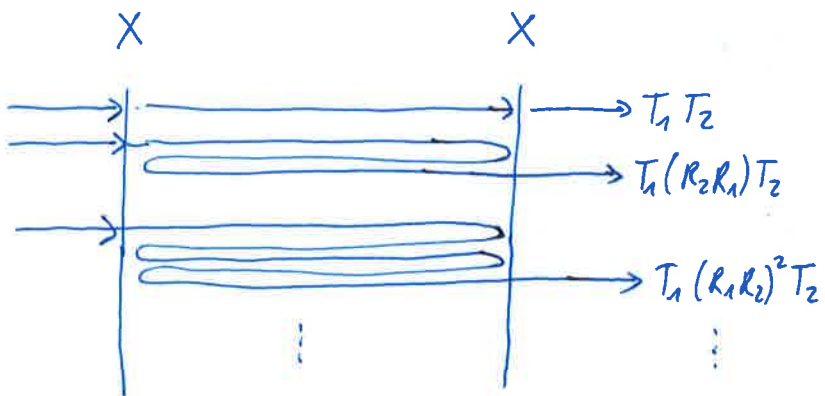
3a) problem in 1D:



number of transverse modes: $M \approx \frac{2k_F}{\Delta k} = \frac{2k_F L_x}{\pi} = \frac{k_F L_x}{\pi}$
see problem 1

b) $G = \frac{2e^2}{h} \cdot M \cdot T = \frac{2e^2}{h} \cdot \frac{k_F L_x}{\pi} \cdot T = \frac{2e^2}{2\pi\hbar} \cdot \underbrace{\frac{mv_F}{\hbar}}_{k_F} \cdot \frac{L_x}{\pi} T = \frac{m}{\hbar^2 \pi} L_x k_F e^2 T / \pi = \underline{\underline{e^2 L_x N \frac{v_F T}{\pi}}}$

c) scatterer 1 scatterer 2



"Feynman paths"

$$\begin{aligned} T_{12} &= T_1 T_2 \cdot \sum_{n=0}^{\infty} (R_1 R_2)^n \\ &= \frac{T_1 T_2}{1 - R_1 R_2} \\ &\uparrow \text{geometric series} \\ &= \frac{T_1 T_2}{1 - (1-T_1)(1-T_2)} \end{aligned}$$

$R_i = 1 - T_i$

d) $\frac{1 - T_{12}}{T_{12}} = \frac{1 - \frac{T_1 T_2}{1 - R_1 R_2}}{\frac{T_1 T_2}{1 - R_1 R_2}} = \frac{1 - R_1 R_2 - T_1 T_2}{T_1 T_2} = \frac{1 - (1-T_1)(1-T_2) - T_1 T_2}{T_1 T_2} = \frac{1 - 1 + 2T_1 T_2 + T_1 + T_2}{T_1 T_2}$
 $= \left(\frac{1}{T_1} - 1\right) + \left(\frac{1}{T_2} - 1\right) = \underline{\underline{\frac{1-T_1}{T_1} + \frac{1-T_2}{T_2}}}$

e) $\frac{1-T}{T}$ is additive (see 3d) $\Rightarrow \frac{1-T_M}{T_M} = M \cdot \frac{1-T}{T}$

$\Rightarrow \frac{1}{T_M} - 1 = M \cdot \frac{1-T}{T}$

$\frac{1}{T_M} = 1 + M \frac{1-T}{T} = \frac{T + M(1-T)}{T}$ or $\underline{\underline{T_M = \frac{T}{T + M(1-T)}}}$

$$3f) \quad T_L = T_M|_{M=L \cdot v} = \frac{T}{T + L \cdot v (1-T)}$$

$$\frac{1}{T_L} = 1 + L \cdot v \underbrace{\frac{1-T}{T}}_{= \frac{1}{L_0}} = 1 + \frac{L}{L_0} = \frac{L+L_0}{L_0}$$

$$\text{or } \underline{\underline{T_L = \frac{L_0}{L+L_0}}}$$

$$g) \quad \overset{\text{from b}}{G} = e^2 N L_x \frac{v_F T_L}{\pi} = \frac{1}{\pi} \underbrace{e^2 N}_{\sigma/D} \cdot v_F L_x \underbrace{\frac{L_0}{L+L_0}}_{T_L} = \frac{\sigma}{D} \cdot \underbrace{\frac{v_F L_0}{\pi}}_D \cdot \frac{L_x}{L+L_0} = \underline{\underline{\sigma \cdot \frac{L_x}{L+L_0}}}$$

$$\underline{\underline{R = \frac{1}{G} = \frac{L+L_0}{\sigma \cdot L_x} = \underbrace{\frac{1}{\sigma} \cdot \frac{L}{L_x}} + \underbrace{\frac{1}{\sigma} \frac{L_0}{L_x}}}}$$

Ohm's law:

$$- \rho = \frac{1}{\sigma} \text{ (resistivity)}$$

$$- \propto L$$

$$- \propto \frac{1}{L_x}$$

contact resistance $\propto \frac{1}{L_x}$